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ISL9R8120P2, ISL9R8120S3S_8 A, 1200 V, STEALTH™ Diode

Symbol

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June 2002

FAIRCHILD

SEMICONDUCTOR®

ISL9R8120P2, ISL9R8120S3S

Features

- Stealth Recovery t_{rr} = 300 ns (@ I_F = 8 A)
- Max Forward Voltage, V_F = 3.3 V (@ T_C = 25°C)
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS compliant

Applications

- Switch Mode Power Supplies
- Hard Switched PFC Boost Diode
- UPS Free Wheeling Diode
- Motor Drive FWD
- SMPS FWD
- Snubber Diode

Package

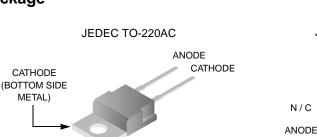
8 A, 1200 V, STEALTH™ Diode

The ISL9R8120P2, ISL9R8120S3S is a STEALTH[™] diode optimized for low loss performance in high frequency hard switched applications. The STEALTH[™] family exhibits low reverse recovery current (I_{RM(REC)}) and exceptionally soft recovery under typical operating conditions. This device is intended for use as a free wheeling or boost diode in power supplies and other power switching applications. The low I_{RM(REC)} and short ta phase reduce loss in switching transistors. The soft recovery minimizes ringing, expanding the range of conditions under which the diode may be operated without the use of additional snubber circuitry. Consider using the STEALTH[™] diode with an SMPS IGBT to provide the most efficient and highest power density design at lower cost.

JEDEC TO-263AB

CATHODE

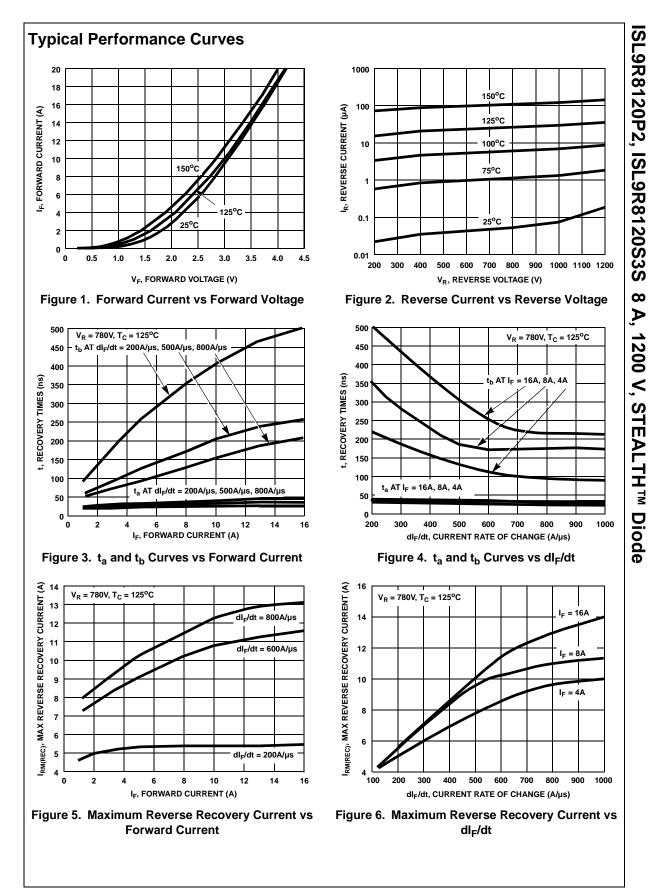
(FLANGE)

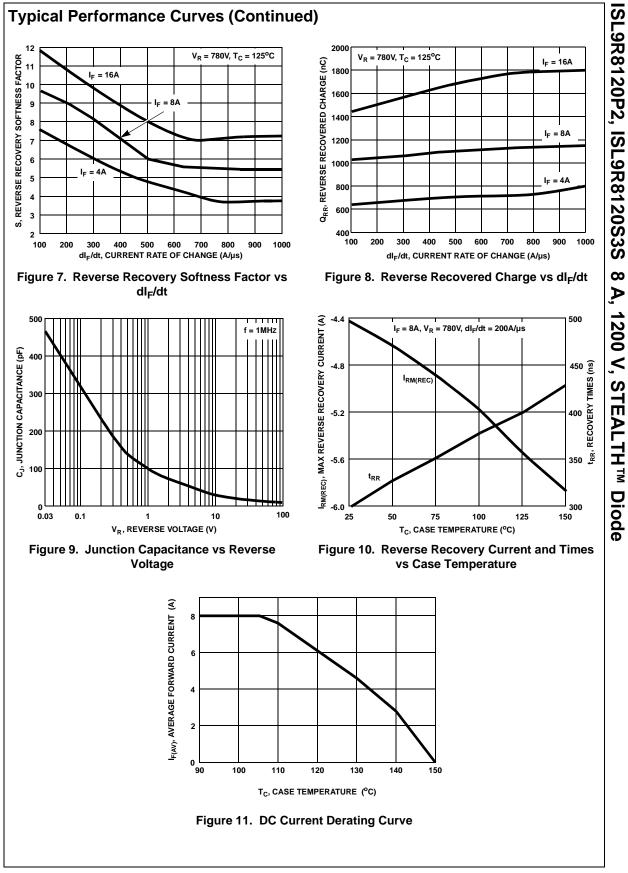


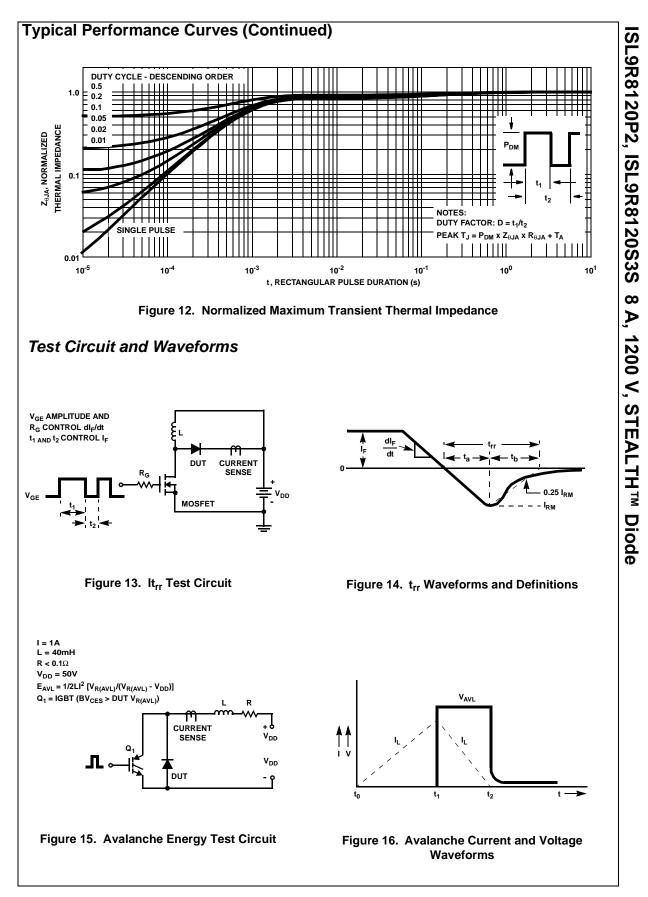
Device Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit V	
V _{RRM}	Repetitive Peak Reverse Voltage	1200		
V _{RWM}	Working Peak Reverse Voltage	1200	V	
V _R	DC Blocking Voltage	1200	V	
I _{F(AV)}	Average Rectified Forward Current (T _C = 105°C)	8	A	
I _{FRM}	Repetitive Peak Surge Current (20 kHz Square Wave)	16	A	
I _{FSM}	Nonrepetitive Peak Surge Current (Halfwave 1 Phase 60 Hz)	100	A	
PD	Power Dissipation	71	W	
E _{AVL}	Avalanche Energy (1 A, 40 mH)	20	m	
Г _Ј , Т _{STG}	Operating and Storage Temperature Range	-55 to 150	°C	
ΤL	Maximum Temperature for Soldering			
T _{PKG}	Leads at 0.063 in (1.6 mm) from Case for 10 s	300	°C	
	Package Body for 10s, See Application Note AN-7528	260	°C	

Device	Device Marking Device		Package Tape Width				Quan	tity
R8120P2 ISL9R8120P2		ISL9R8120P2	TO-220AC	N/A			50	
R8120S3S ISL9R8120S3S			TO-263AB 24mm				800	
lectri	cal Chai	acteristics τ _c = 25°C u	nless otherwise	e noted				
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Unit
ff State	e Charact	eristics						
I _R	Instantaneous Reverse Current		V _R = 1200 V	T _C = 25°C	-	-	100	μA
				T _C = 125°C	-	-	1.0	mA
n State	e Charact	eristics						
V _F	Instantane	ous Forward Voltage	I _F = 8 A	T _C = 25°C	-	2.8	3.3	V
·				T _C = 125°C	-	2.7	3.1	V
vnami	c Charact	eristics	•			•	•	
CJ		apacitance	V _R = 10 V, I _F = 0 A		-	30	-	pF
								·
	ng Charac							
t _{rr}	Reverse R	ecovery Time		= 100 A/µs, V _R = 30 V	-	25	32	ns
			$I_F = 8 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	35	44	ns
t _{rr}		ecovery Time	I _F = 8 A, dI _F /dt = 200 A/μs, V _R = 780 V, T _C = 25°C		-	300	-	ns
I _{rr}		ecovery Current			-	4.3	-	A
Q _{rr}		ecovered Charge			-	525	-	nC
t _{rr}		ecovery Time	$I_F = 8 A,$	_	-	375	-	ns
S		actor (t _b /t _a)	dI _F /dt = 200 A/µ V _R = 780 V,	IS,	-	9	-	-
۱ _{rr}		ecovery Current	T _C = 125°C		-	5.5	-	A
Q _{rr}	Reverse R	ecovered Charge	$1_{\rm C} = 123$ C		-	1.1	-	μC
t _{rr}		ecovery Time	I _F = 8 A,		-	200	-	ns
S	Softness F	actor (t _b /t _a)	dI _F /dt = 1000 A/ V _R = 780 V,	μs,	-	5.5	-	-
l _{rr}	Reverse R	ecovery Current	T _C = 125°C		-	11	-	Α
Q _{rr}	Reverse R	ecovered Charge			-	1.2	-	μC
dl _M /dt	Maximum	di/dt during t _b			-	310	-	A/µs
	Characte	eristics						
nerma	Thormol D	esistance Junction to Case	TO-220, TO-263		-	-	1.75	°C/W
nerma R _{θJC}	Thermal R		TO-220, TO-263				62	°C/W







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A, 1200 V, STEALTH[™] Diode



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Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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		Rev. 164

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